Fast Recovery Diodes (Hockey PUK Version), 810 A/910 A

B-43

FEATURES

- High power FAST recovery diode series
- 2.0 µs to 3.0 µs recovery time
- High voltage ratings up to 2500 V
- High current capability
- Optimized turn-on and turn-off characteristics
- Low forward recovery
- Fast and soft reverse recovery
- Press PUK encapsulation
- Hockey PUK version case style B-43
- Maximum junction temperature 150 °C
- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

Pb-free RoHS COMPLIANT

TYPICAL APPLICATIONS

- Snubber diode for GTO
- High voltage freewheeling diode
- Fast recovery rectifier applications

PRODUCT SUMMARY	
$I_{F(AV)}$	810A /910 A
Package	B-43
Circuit configuration	Single diode

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	SD823C..C		UNITS
		S20	S30	
$I_{F(AV)}$		810	910	A
	T_{hs}	55	55	°C
$I_{F(RMS)}$		1500	1690	A
I_{FSM}	50 Hz	9300	9600	
	60 Hz	9730	10 050	
V_{RRM}	Range	1200 to 2500	1200 to 2500	V
t_{rr}		2.0	3.0	µs
	T_J	25		°C
T_J		- 40 to 150		

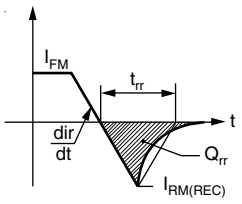
ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	V_{RRM}, MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM}, MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA
VS-SD823C..C	12	1200	1300	50
	16	1600	1700	
	20	2000	2100	
	25	2500	2600	

FORWARD CONDUCTION

PARAMETER	SYMBOL	TEST CONDITIONS			SD823C..C S20	SD823C..C S30	UNITS
Maximum average forward current at heatsink temperature	$I_{F(AV)}$	180° conduction, half sine wave Double side (single side) cooled			810 (425)	910 (470)	A
					55 (85)	55 (85)	°C
Maximum RMS forward current	$I_{F(RMS)}$	25 °C heatsink temperature double side cooled			1500	1690	A
Maximum peak, one-cycle forward, non-repetitive current	I_{FSM}	t = 10 ms	No voltage reapplied	Sinusoidal half wave, initial $T_J = T_J$ maximum	9300	9600	
		t = 8.3 ms			9730	10 050	
		t = 10 ms	100 % V_{RRM} reapplied		7820	8070	
		t = 8.3 ms			8190	8450	
Maximum I^2t for fusing	I^2t	t = 10 ms	No voltage reapplied		432	460	kA^2s
		t = 8.3 ms			395	420	
		t = 10 ms	100 % V_{RRM} reapplied		306	326	
		t = 8.3 ms			279	297	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 to 10 ms, no voltage reapplied			4320	4600	$kA^2\sqrt{s}$
Low level value of threshold voltage	$V_{F(TO)1}$	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), $T_J = T_J$ maximum			1.00	0.95	V
High level value of threshold voltage	$V_{F(TO)2}$	(I > π x $I_{F(AV)}$), $T_J = T_J$ maximum			1.11	1.06	
Low level value of forward slope resistance	r_{f1}	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), $T_J = T_J$ maximum			0.80	0.60	mW
High level value of forward slope resistance	r_{f2}	(I > π x $I_{F(AV)}$), $T_J = T_J$ maximum			0.76	0.57	
Maximum forward voltage drop	V_{FM}	I_{pk} = 1500 A, $T_J = T_J$ maximum t_p = 10 ms sinusoidal wave			2.20	1.85	V

RECOVERY CHARACTERISTICS

CODE	MAXIMUM VALUE AT T_J = 25 °C	TEST CONDITIONS			TYPICAL VALUES AT T_J = 125 °C			
	t_{rr} AT 25 % I_{RRM} (µs)	I_{pk} SQUARE PULSE (A)	dI/dt (A/µs)	V_r (V)	t_{rr} AT 25 % I_{RRM} (µs)	Q_{rr} (µC)	I_{rr} (A)	
S20	2.0	1000	50	- 50	3.5	240	110	
S30	3.0				5.0	380	130	

THERMAL AND MECHANICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating and storage temperature range	T_J, T_{Stg}		- 40 to 150	°C
Maximum thermal resistance, case junction to heatsink	R_{thJ-hs}	DC operation single side cooled	0.076	K/W
		DC operation double side cooled	0.038	
Mounting force, ± 10 %			9800 (1000)	N (kg)
Approximate weight			83	g
Case style		See dimensions - link at the end of datasheet	B-43	

ΔR_{thJ-hs} CONDUCTION

CONDUCTION ANGLE	SINUSOIDAL CONDUCTION		RECTANGULAR CONDUCTION		TEST CONDITIONS	UNITS
	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE		
180°	0.007	0.007	0.005	0.005	$T_J = T_J$ maximum	K/W
120°	0.008	0.008	0.008	0.008		
90°	0.010	0.010	0.011	0.011		
60°	0.015	0.015	0.016	0.016		
30°	0.026	0.026	0.026	0.026		

Note

- The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC

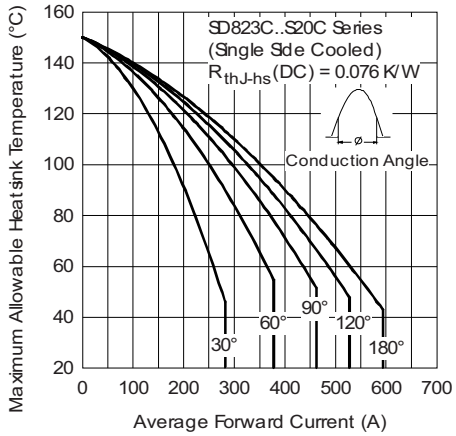


Fig. 1 - Current Ratings Characteristics

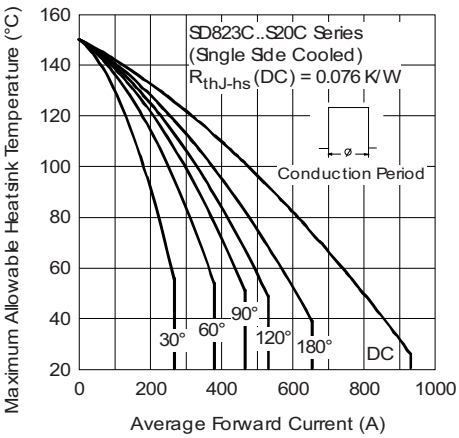


Fig. 2 - Current Ratings Characteristics

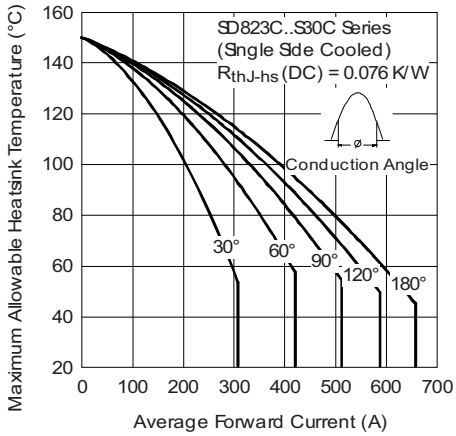


Fig. 3 - Current Ratings Characteristics

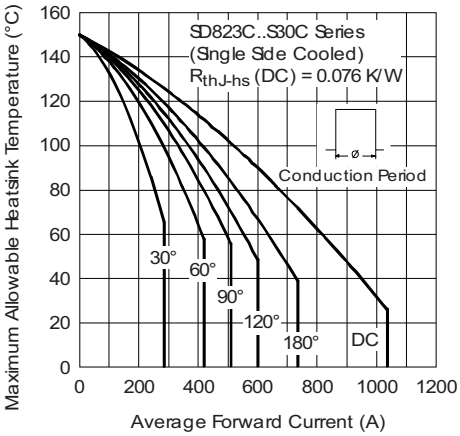


Fig. 4 - Current Ratings Characteristics

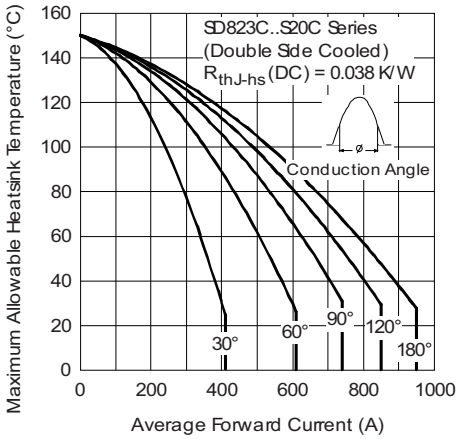


Fig. 5 - Current Ratings Characteristics

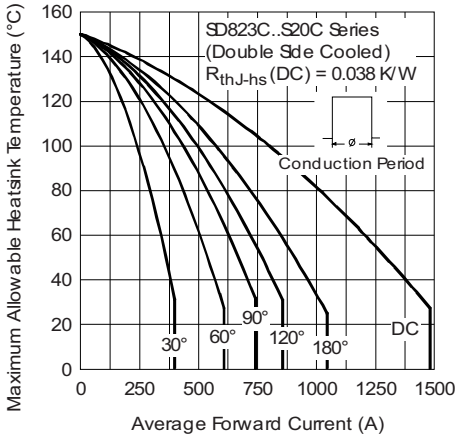


Fig. 6 - Current Ratings Characteristics

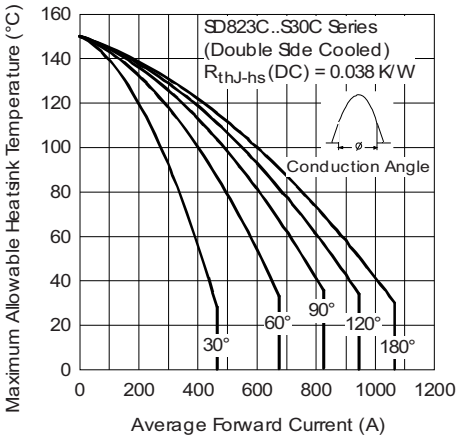


Fig. 7 - Current Ratings Characteristics

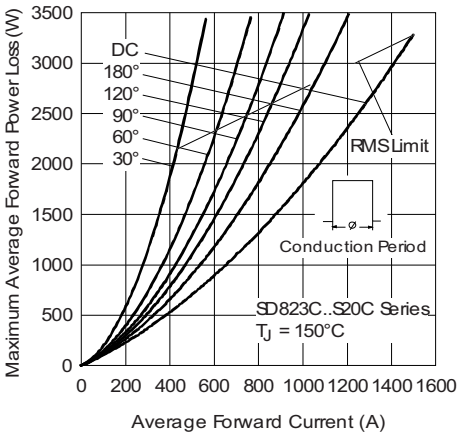


Fig. 10 - Forward Power Loss Characteristics

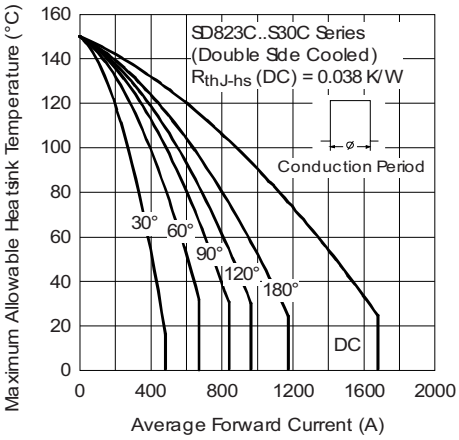


Fig. 8 - Current Ratings Characteristics

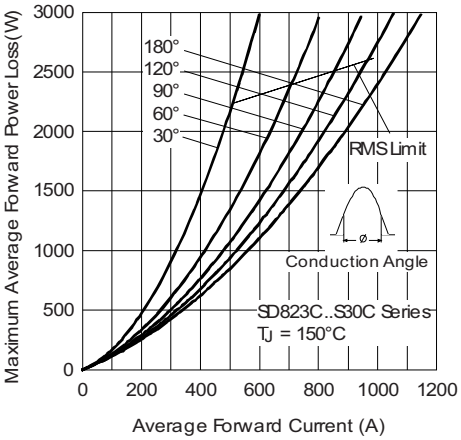


Fig. 11 - Forward Power Loss Characteristics

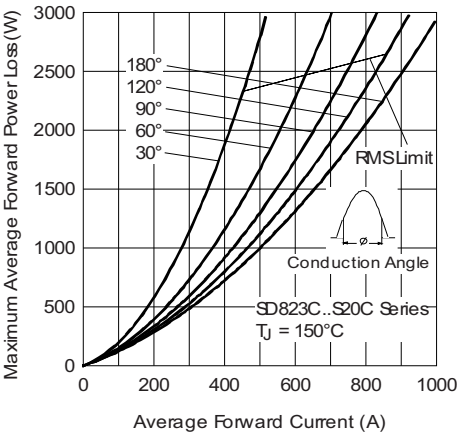


Fig. 9 - Forward Power Loss Characteristics

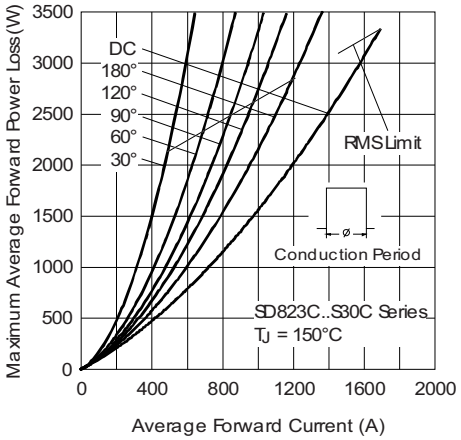


Fig. 12 - Forward Power Loss Characteristics

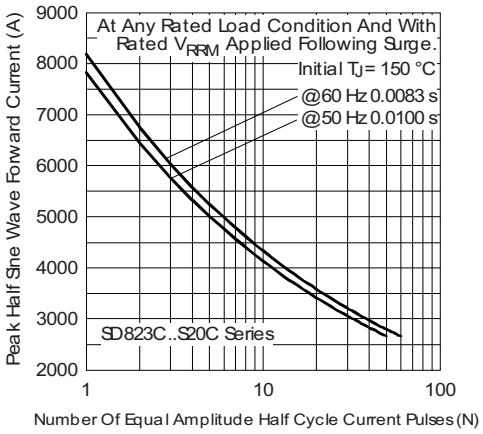


Fig. 13 - Maximum Non-Repetitive Surge Current

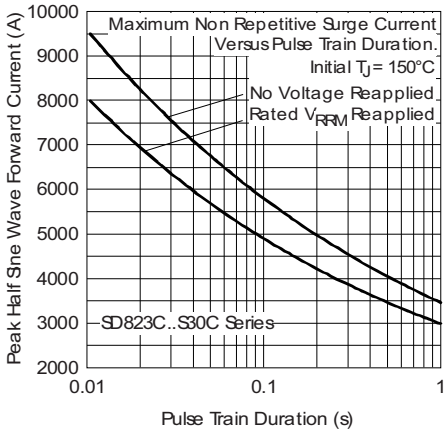


Fig. 16 - Maximum Non-Repetitive Surge Current

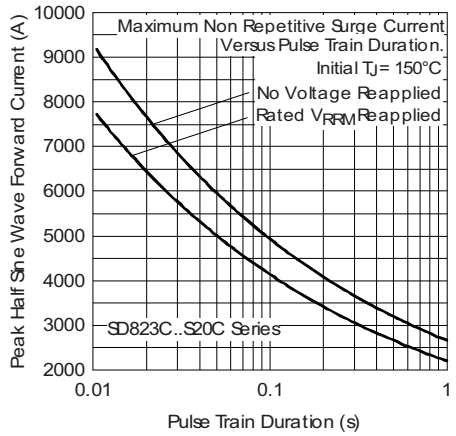


Fig. 14 - Maximum Non-Repetitive Surge Current

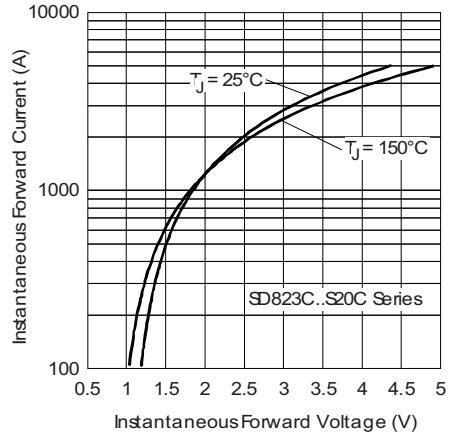


Fig. 17 - Forward Voltage Drop Characteristics

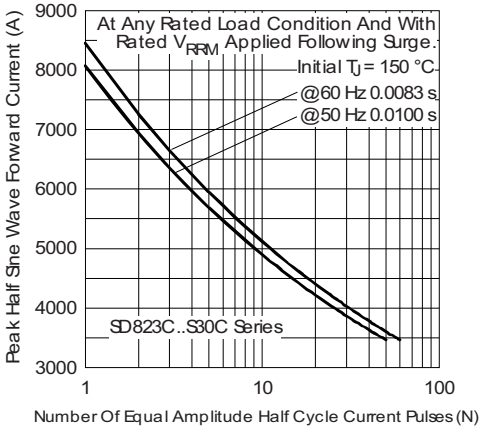


Fig. 15 - Maximum Non-Repetitive Surge Current

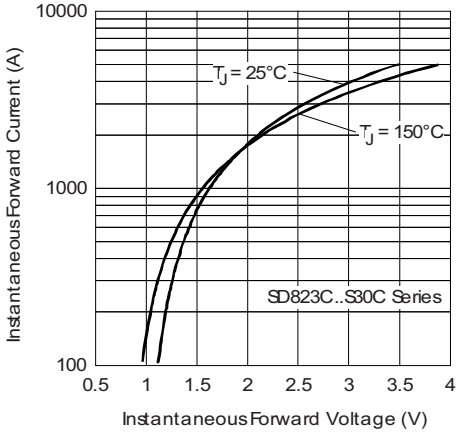


Fig. 18 - Forward Voltage Drop Characteristics

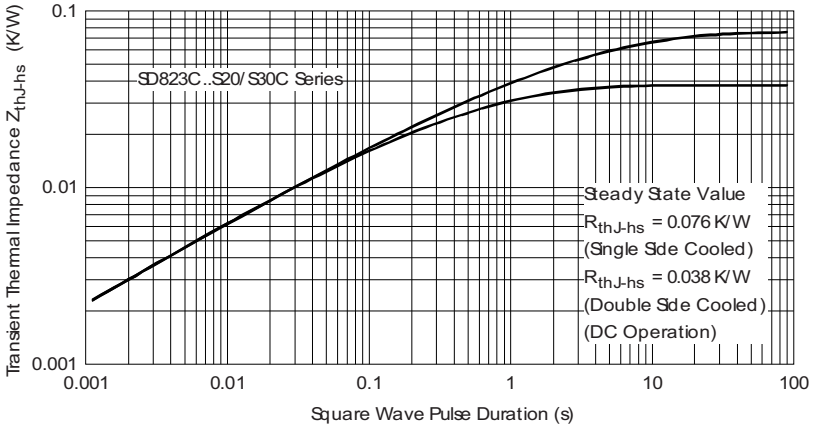


Fig. 19 - Thermal Impedance Z_{thJ-hs} Characteristic

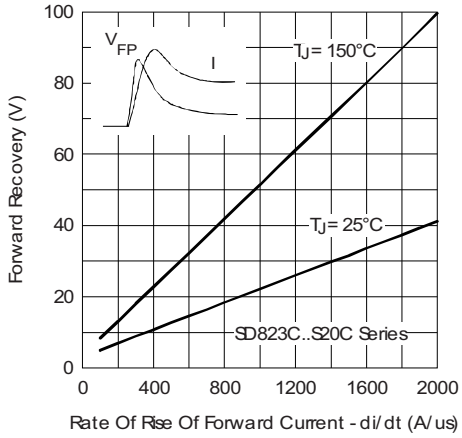


Fig. 20 - Typical Forward Recovery Characteristics

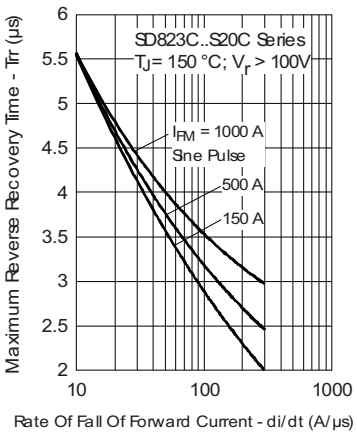


Fig. 22 - Recovery Time Characteristics

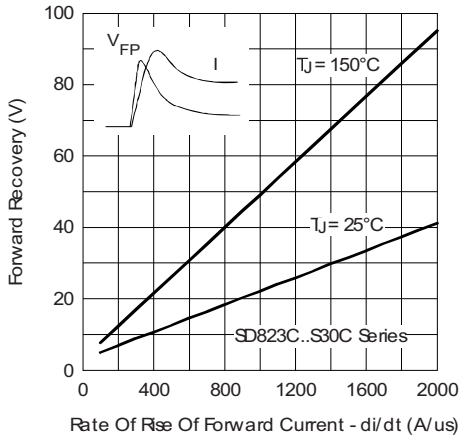


Fig. 21 - Typical Forward Recovery Characteristics

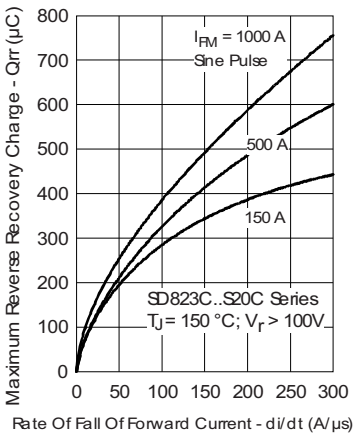


Fig. 23 - Recovery Charge Characteristics

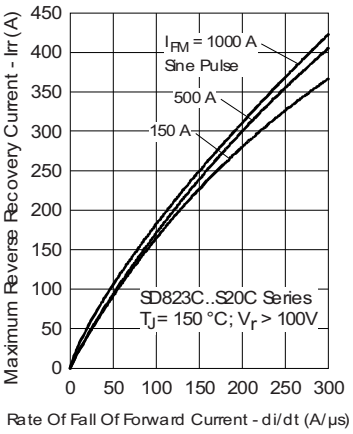


Fig. 24 - Recovery Current Characteristics

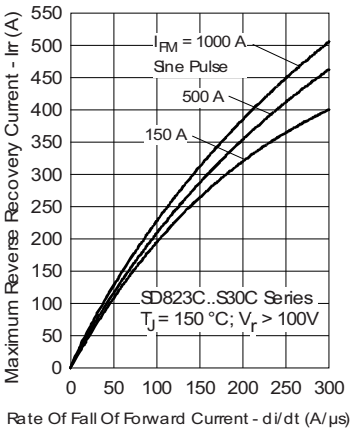


Fig. 27 - Recovery Current Characteristics

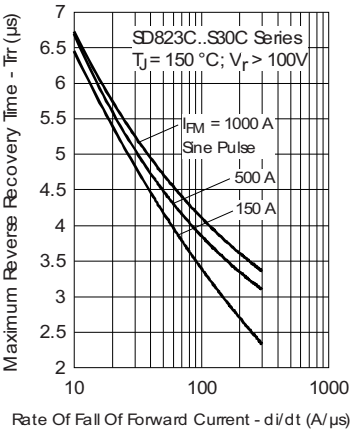


Fig. 25 - Recovery Time Characteristics

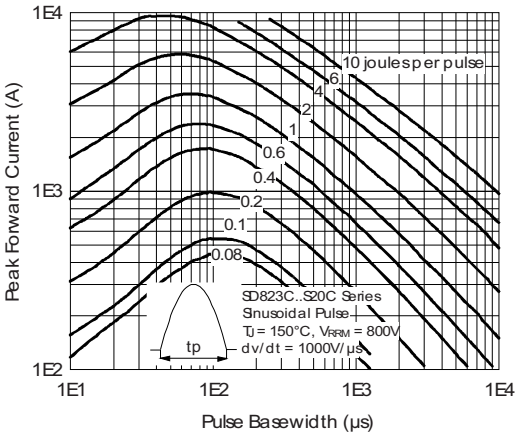


Fig. 28 - Maximum Total Energy Loss Per Pulse Characteristics

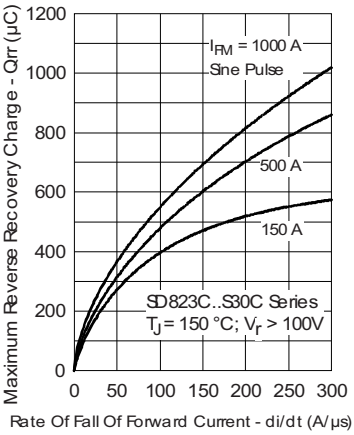


Fig. 26 - Recovery Charge Characteristics

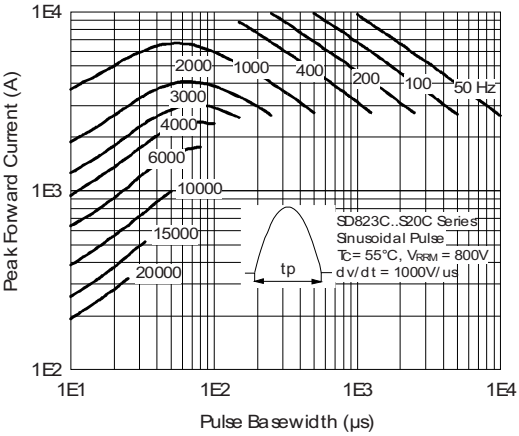


Fig. 29 - Frequency Characteristics

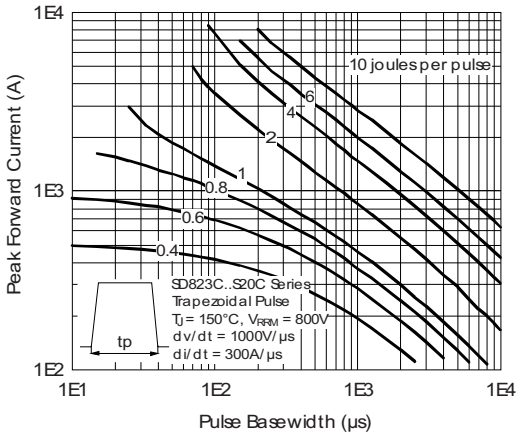


Fig. 30 - Maximum Total Energy Loss Per Pulse Characteristics

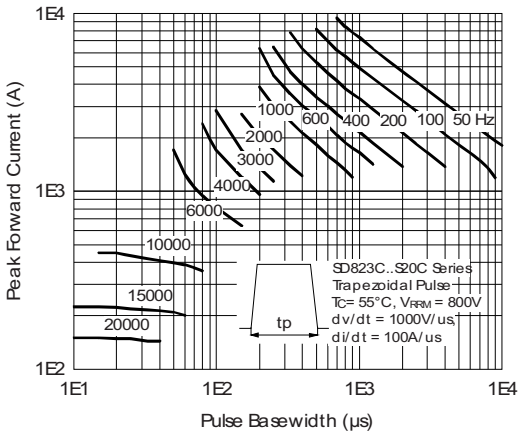


Fig. 33 - Frequency Characteristics

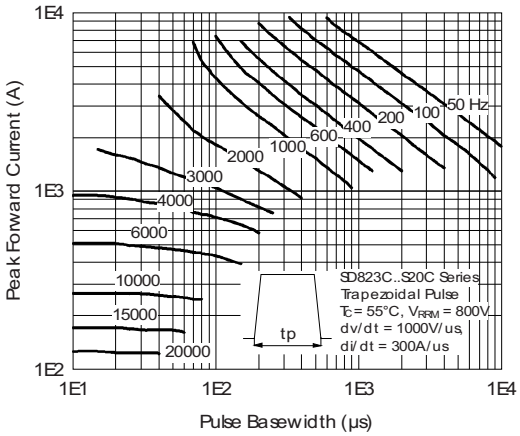


Fig. 31 - Frequency Characteristics

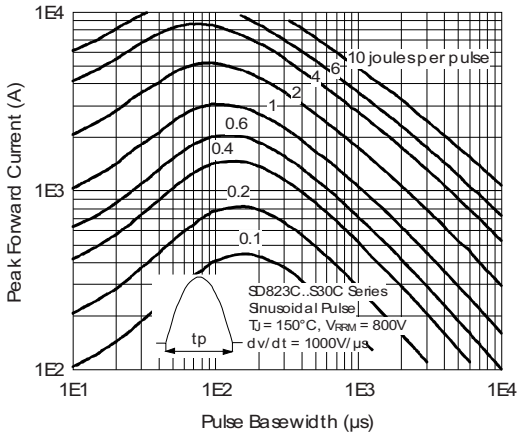


Fig. 34 - Maximum Total Energy Loss Per Pulse Characteristics

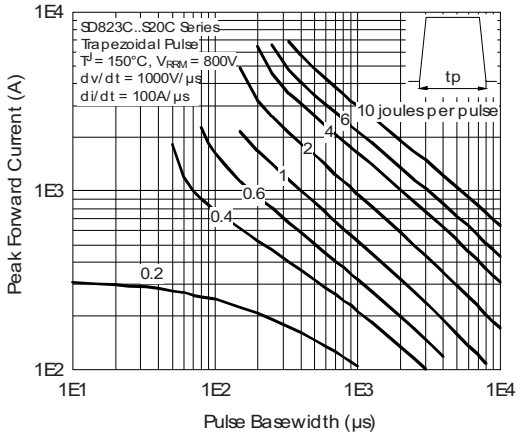


Fig. 32 - Maximum Total Energy Loss Per Pulse Characteristics

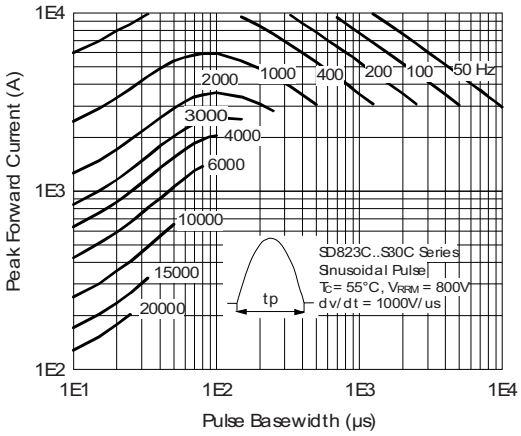


Fig. 35 - Frequency Characteristics

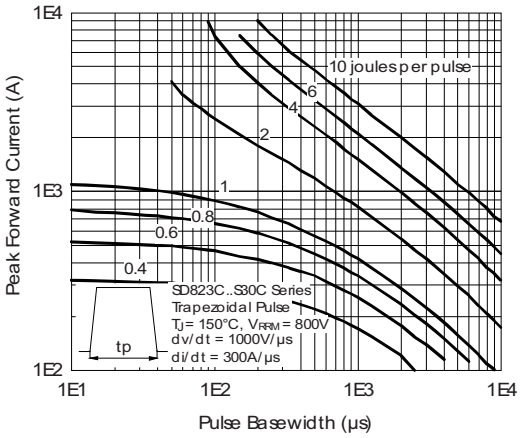


Fig. 36 - Maximum Total Energy Loss Per Pulse Characteristics

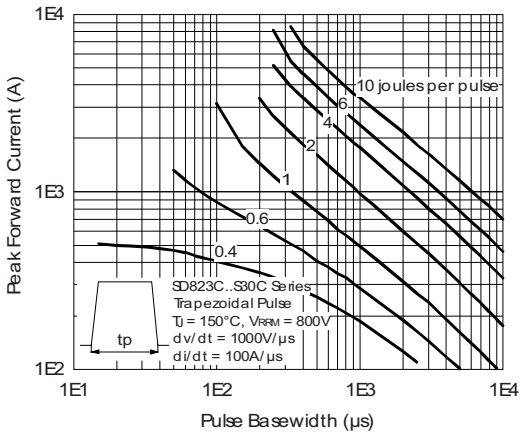


Fig. 38 - Maximum Total Energy Loss Per Pulse Characteristics

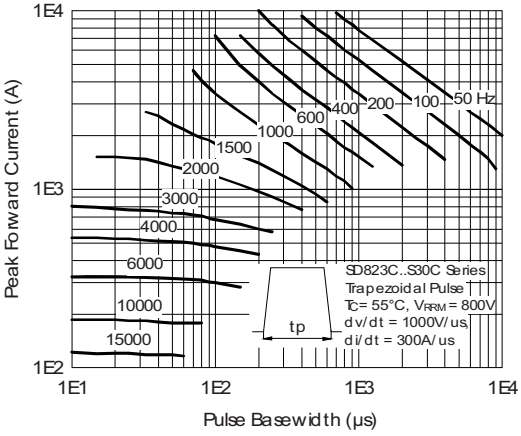


Fig. 37 - Frequency Characteristics

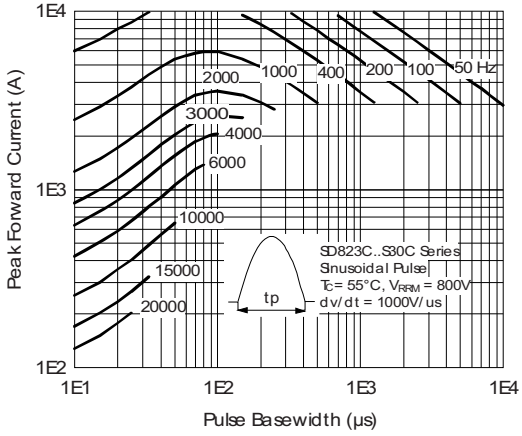


Fig. 39 - Frequency Characteristics

ORDERING INFORMATION TABLE

Device code

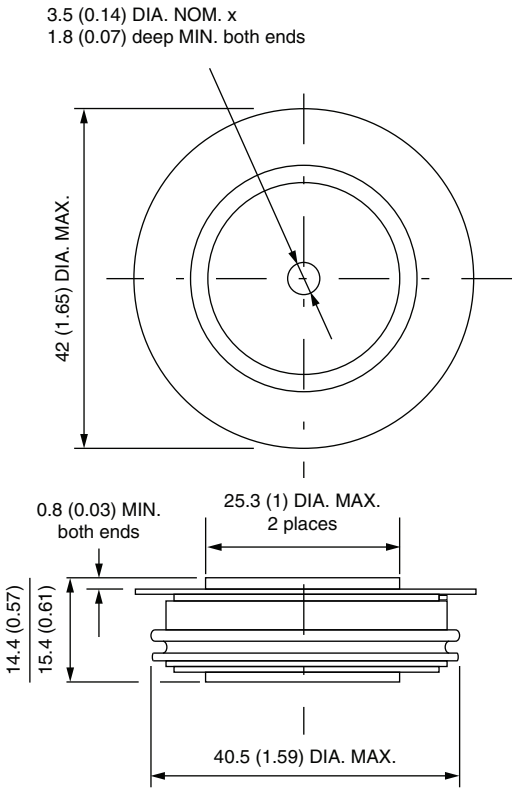
VS-	SD	82	3	C	25	S20	C
1	2	3	4	5	6	7	8

- 1 - Vishay Semiconductors product
- 2 - Diode
- 3 - Essential part number
- 4 - 3 = Fast recovery
- 5 - C = Ceramic PUK
- 6 - Voltage code x 100 = V_{RRM} (see Voltage Ratings table)
- 7 - t_{rr} code
- 8 - C = PUK case B-43

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95249

B-43

DIMENSIONS in millimeters (inches)



Quote between upper and lower pole pieces has to be considered after application of mounting force (see Thermal and Mechanical Specifications)

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Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001
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